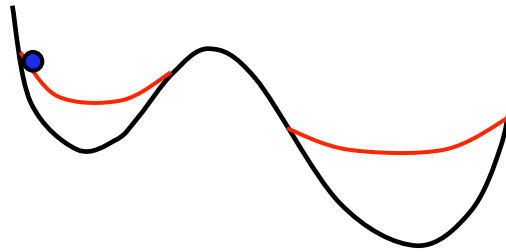


Hyperdynamics

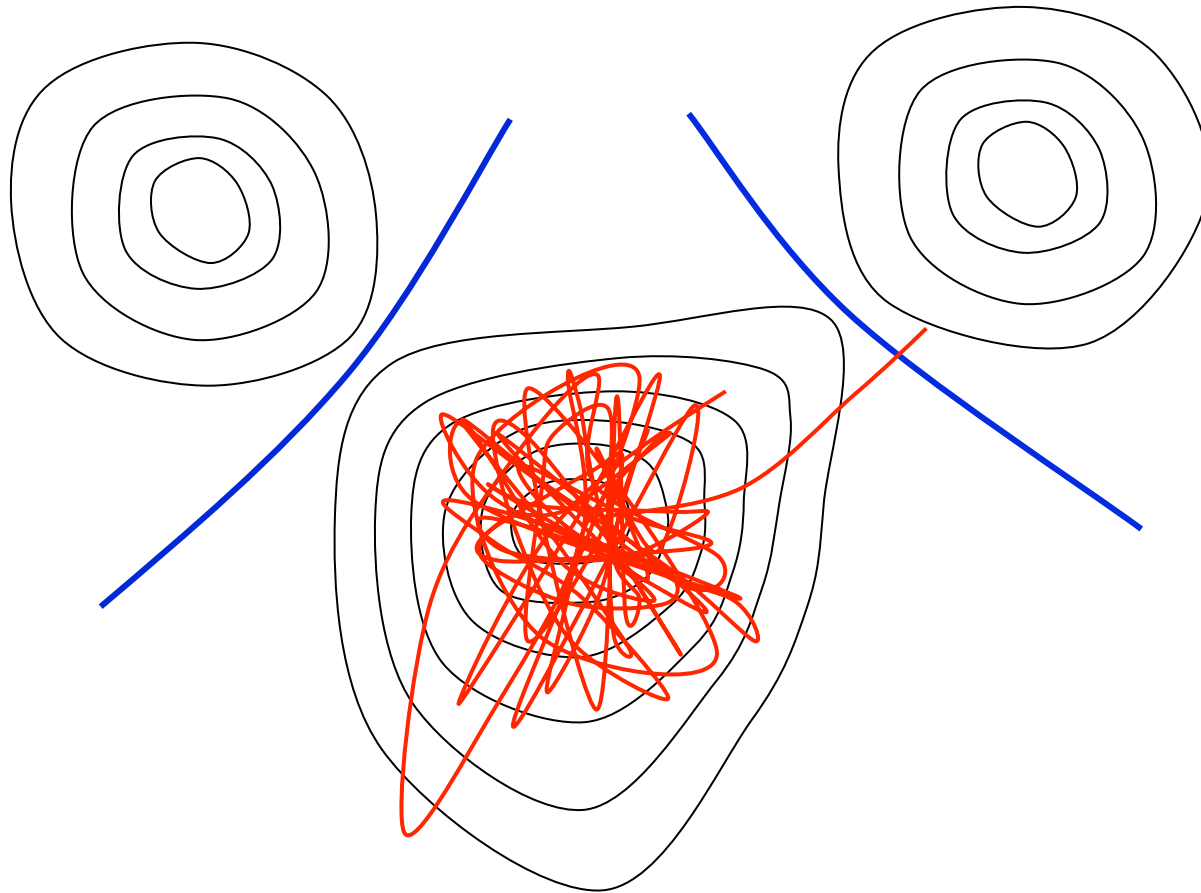


A very brief introduction

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Infrequent-Event System



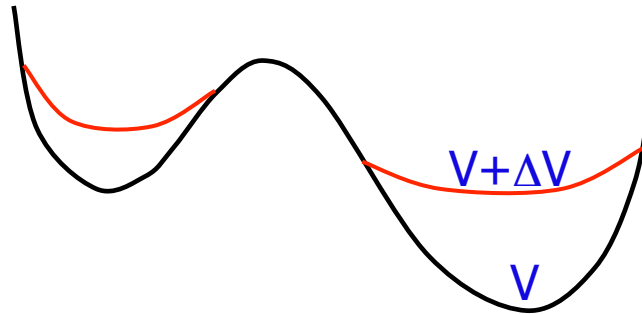
The system vibrates in 3-N dimensional basin many times before finding an escape path. In hyperdynamics, we partially fill in the basins with a bias potential to cause the trajectory to find an appropriate escape path more quickly.

Hyperdynamics

Builds on umbrella-sampling techniques (e.g., Valleau 1970's)

Assumptions:

- infrequent events
- transition state theory (no recrossings)



Procedure:

- design bias potential ΔV (zero at dividing surfaces)
- run thermostatted trajectory on the biased surface ($V+\Delta V$)
- accumulate hypertime as

$$t_{\text{hyper}} = \sum \Delta t_{\text{MD}} \exp[\Delta V(R(t))/k_B T]$$

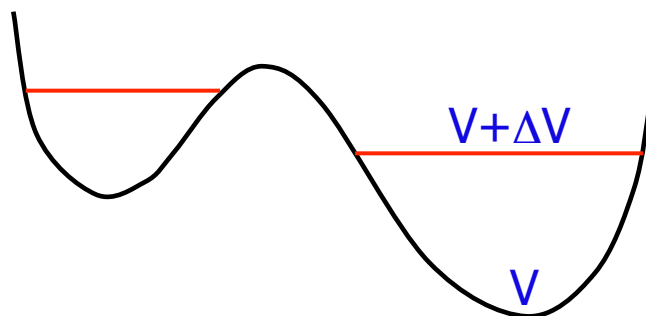
- time converges on correct value in long-time limit (w/ vanishing relative error)

AFV, J. Chem. Phys. 106, 4665 (1997)

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Hyperdynamics bias potential

An extremely simple form: flat bias potential



M. M. Steiner, P.-A. Genilloud, and J. W. Wilkins, Phys. Rev. B **57**, 10236 (1998).

- no more expensive than normal MD (negative overhead(!))
- very effective for low-dimensional systems
- diminishing boost factor for more than a few atoms.

Hyperdynamics - characteristics

Designing valid and effective bias potential is the key challenge.

Bias potential can be a function of

- the shape of the energy surface (AFV, 1997)
- the energy (Steiner, Genilloud and Wilkins, 1998)
- the geometry
 - bond lengths, Miron and Fichthorn, 2003, 2005
 - local strain, Hara and Li, 2010

Must be careful that bias is zero on all dividing surfaces or dynamics will be wrong.

When barriers are high relative to T , boost can be many orders of magnitude.

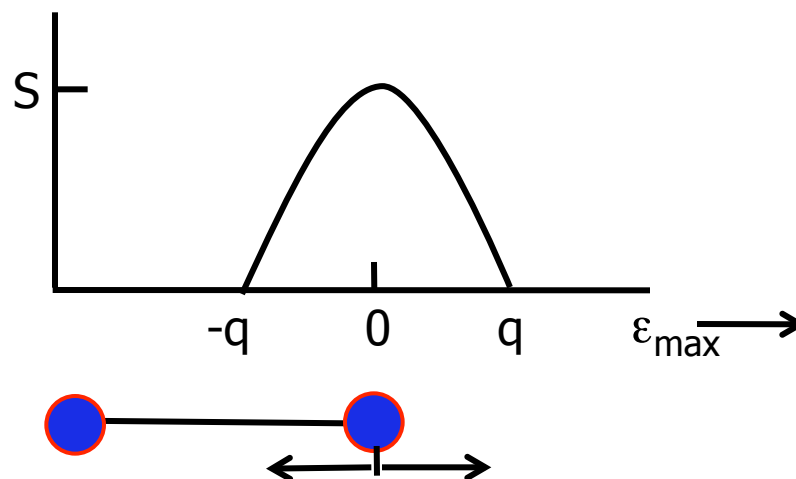
Simplified bond-boost bias potential

Based on Miron-Fichthorn 2003 form [R.A. Miron and K.A. Fichthorn, J. Chem. Phys. **119**, 6210 (2003)], but simplified.

Bias potential turns off when the relative distortion [$\epsilon_{ij} = (r_{ij} - r_{ij}^{\min})/r_{ij}^{\min}$] of any bond exceeds a threshold value q (as in Miron-Fichthorn 2003).

Simplification: ΔV depends purely on coordinate (ϵ_{\max}) of most-distorted bond. Only one bond at a time has any bias force.

$$\Delta V(\epsilon_{\max}) = S[1 - (\epsilon_{\max}/q)^2]$$



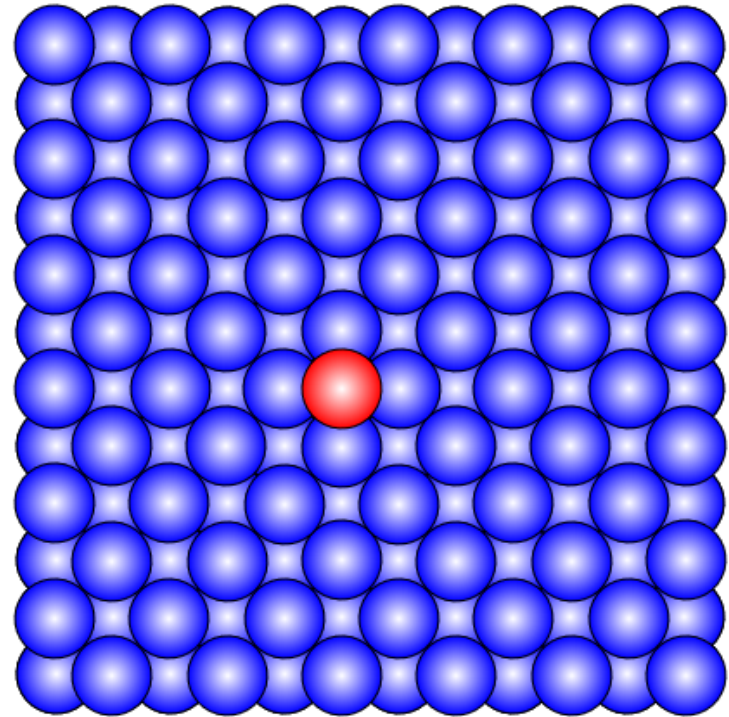
Simple bond-boost bias example

Simple bond-boost bias potential

Cu adatom on Cu(100) surface

Hop barrier = 0.53 eV

<u>T(K)</u>	<u>hop time</u>	<u>boost factor</u> (S=0.4 eV)
350 K	1.36 μ s *	1.1×10^3
300 K	27 μ s	3.1×10^4
200 K	0.8 s	1.1×10^8

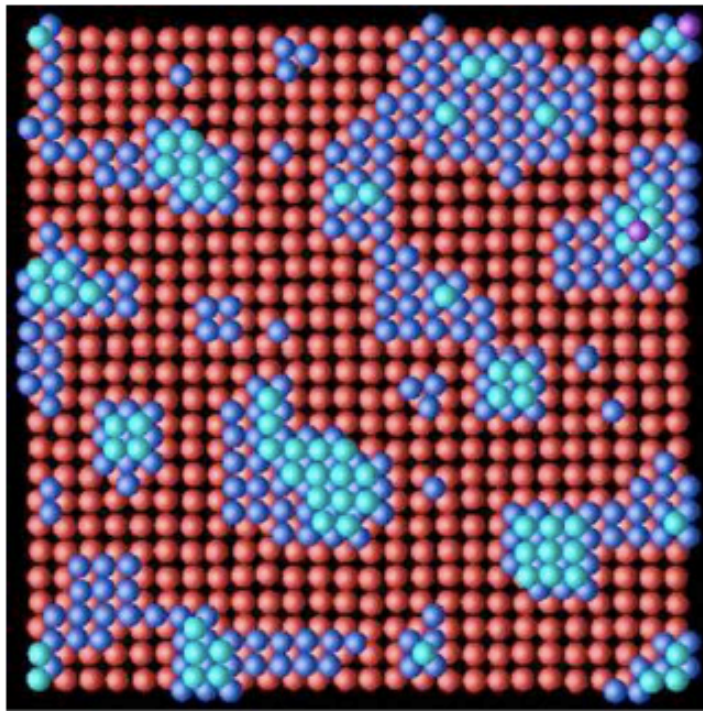


*At T=350K, the hyperdynamics rate matches full harmonic TST ("Vineyard") rate within 5% error bars (743 events).

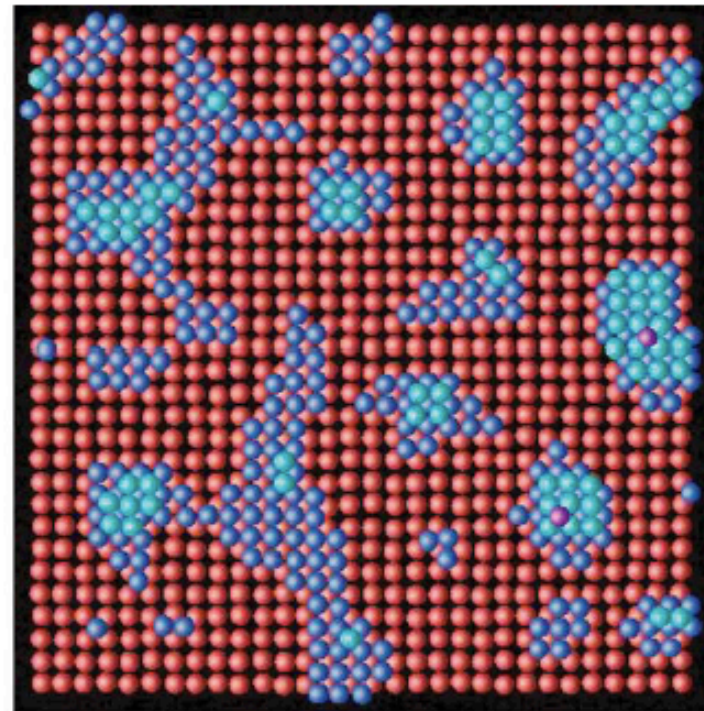
Hyperdynamics example from Kristen Fichthorn's group

Miron and Fichthorn Phys. Rev. B 72, 035415 (2005)

Co/Cu(001) growth at experimental deposition rates using bond-boost bias potential and bond-bridging for low barriers.



T=250K, t=0.54 s (0.1 ML/s)



T=310K, t=0.42 s (1.0 ML/s)